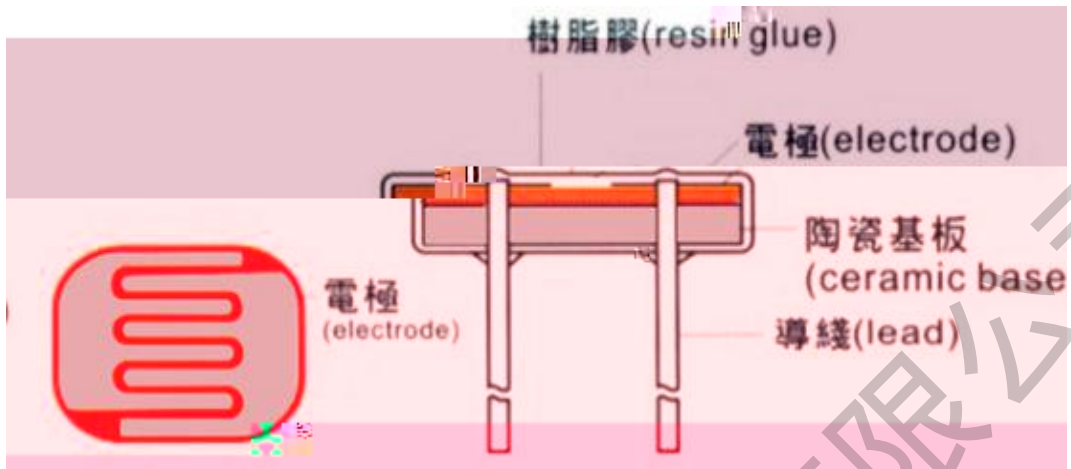




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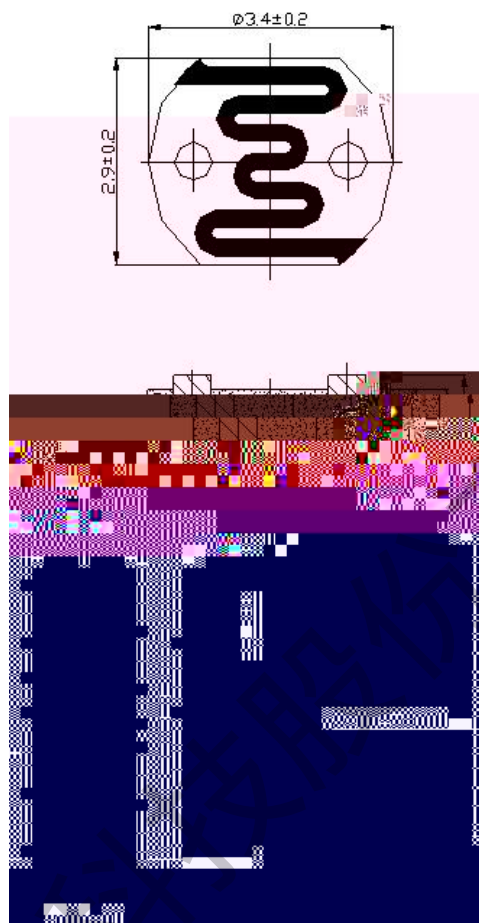


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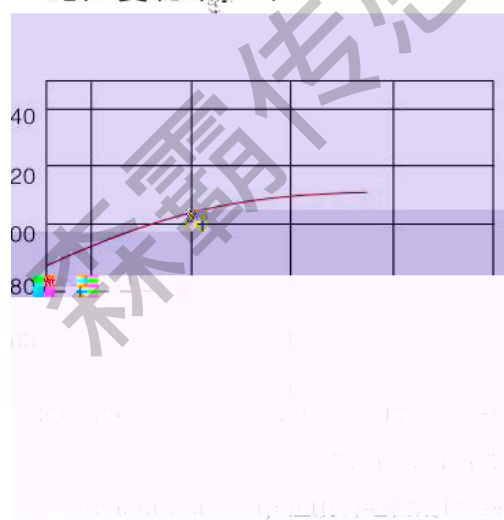
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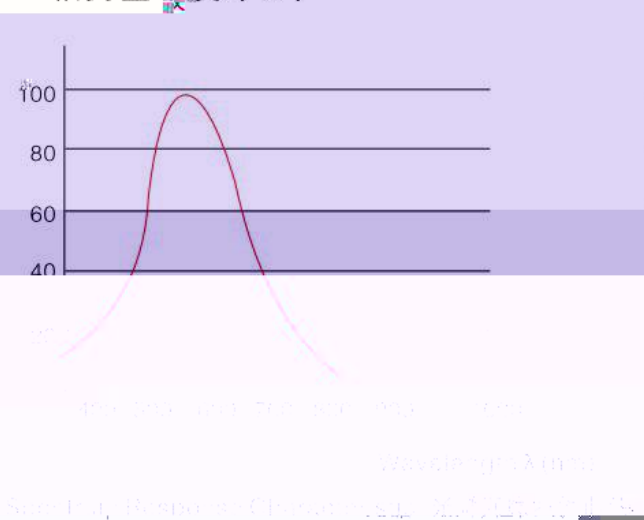
		VDC	mw			nm	10Lux (KΩ)	MΩ	y 100			
									10	(ms)		
Ø3	GL3516	100	50	-30	+70	540	5-10	0.6	0.5	30	30	2
	GL3526	100	50	-30	+70	540	10-20	1	0.6	30	30	3
	GL3537-1	100	50	-30	+70	540	20-30	2	0.6	30	30	4
	GL3537-2	100	50	-30	+70	540	30-50	3	0.7	30	30	4
	GL3547-1	100	50	-30	+70	540	50-100	5	0.8	30	30	6
	GL3547-2	100	50	-30	+70	540	100-200	10	0.9	30	30	6

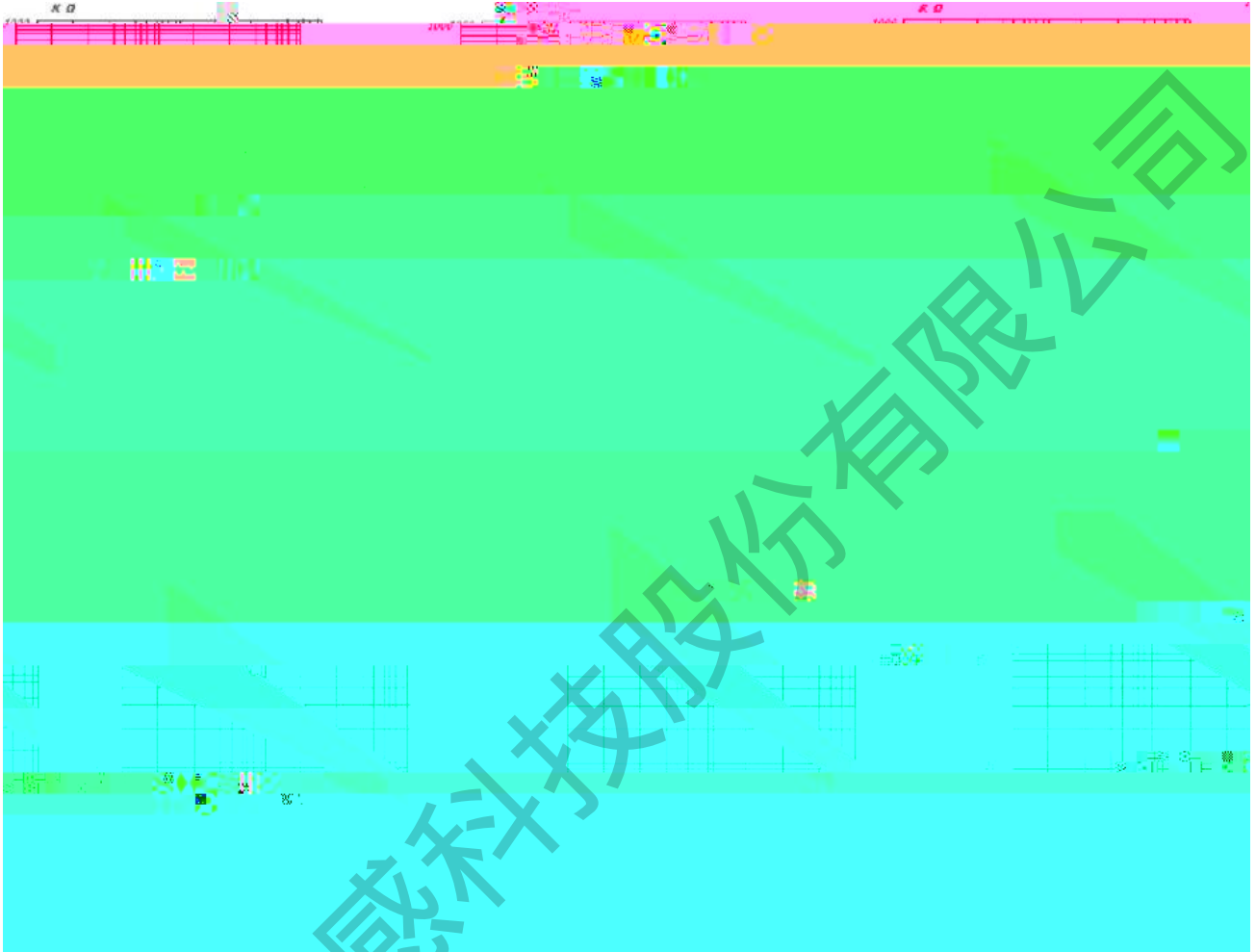
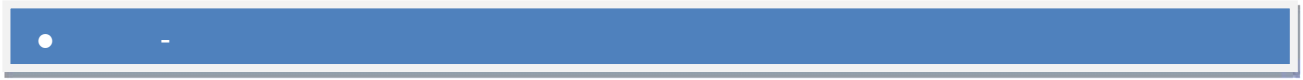


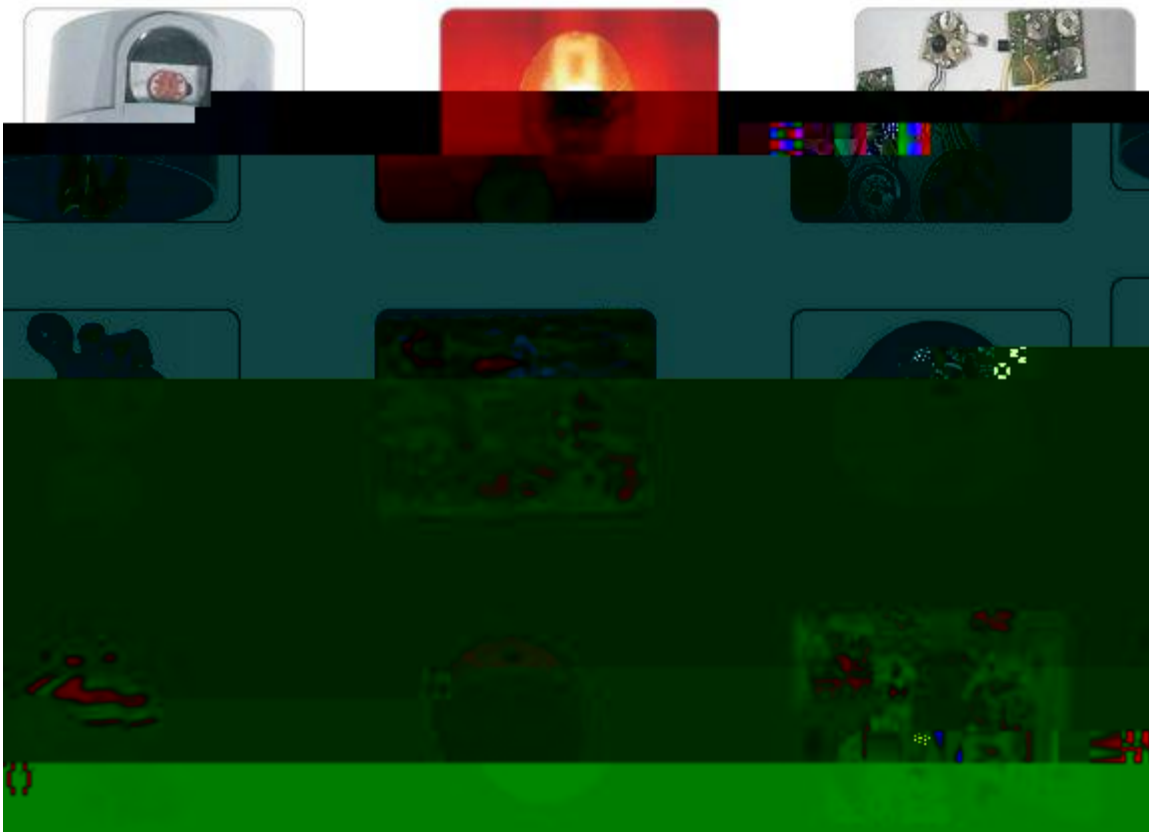
Relative Resistance (%)
电阻变化率 (%)



Relative Response (%)
相对灵敏度 (%)







- 200